Vishay General Semiconductor

Surface-Mount Ultrafast Plastic Rectifier



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SMC (DO-214AB) Cathode O Anode

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	3.0 A				
V _{RRM}	100 V, 150 V, 200 V				
t _{rr}	25 ns				
V _F	0.90 V				
T _J max.	175 °C				
Package	SMC (DO-214AB)				
Circuit configuration	Single				

FEATURES

- Glass passivated pellet chip junction
- · Ideal for automated placement
- Ultrafast recovery times for high efficiency

ESH3B-M3, ESH3C-M3, ESH3D-M3

- Low forward voltage, low power loss
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both consumer, and automotive.

MECHANICAL DATA

Case: SMC (DO-214AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT
Device marking code		EHB	EHC	EHD	
Maximum repetitive peak reverse voltage	V _{RMM}	100	150	200	
Maximum RMS voltage	V _{RMS}	70	105	140	V
Maximum DC blocking voltage	V _{DC}	100	150	200	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	3.0			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	125			A
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175			°C



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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage	I _F = 3 A		V _F ⁽¹⁾	0.90	V	
Maximum DC reverse current	7	T _A = 25 °C		5.0		
at rated DC blocking voltage		T _A = 125 °C	IR	150	μΑ	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	25		
Typical reverse recovery time	IF = 074, VR = 00 V,	T _J = 25 °C	- t _{rr}	40	ns	
		T _J = 100 °C		55		
Typical stored charge	I _F = 3 A, V _B = 30 V,	$T_{\rm J} = 3$ A, $V_{\rm B} = 30$ V, $T_{\rm J} = 25$ °C	0	25	nC	
	dl/dt = 50 A/µs, I _{rr} = 10 % I _{RM} T _J = 100 °C	T _J = 100 °C	Q _{rr}	60		
Typical junction capacitance	4.0 V, 1 MHz		CJ	70	pF	

Note

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT
Typical thermal resistance	R _{0JA} ⁽¹⁾	50			°C/W
rypical mermanesistance	R _{θJL} ⁽¹⁾	15			

Note

⁽¹⁾ Units mounted on PCB with 12.0 mm x 12.0 mm land areas

ORDERING INFORMATION (Example)							
PREFERRED P/N	ERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE		BASE QUANTITY	DELIVERY MODE			
ESH3D-M3/57T	0.211	57T	850	7" diameter plastic tape and reel			
ESH3D-M3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel			



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

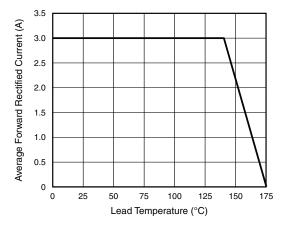


Fig. 1 - Maximum Forward Current Derating Curve

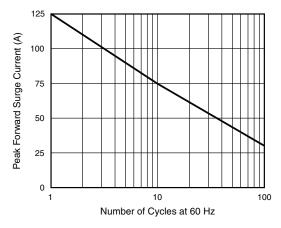


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

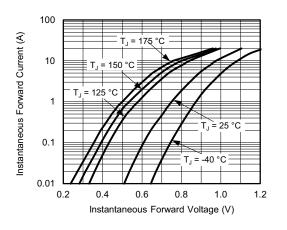


Fig. 3 - Typical Instantaneous Forward Characteristics

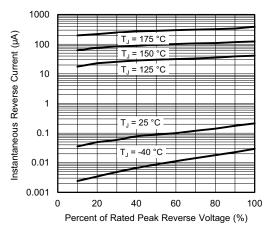


Fig. 4 - Typical Reverse Leakage Characteristics

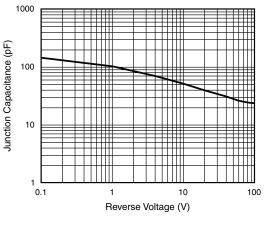


Fig. 5 - Typical Junction Capacitance

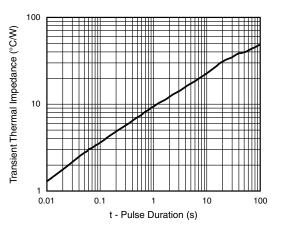


Fig. 6 - Typical Transient Thermal Impedance

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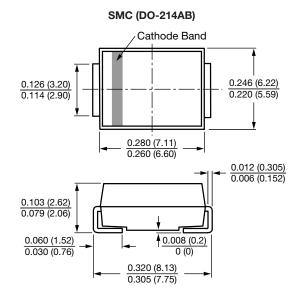


ESH3B-M3, ESH3C-M3, ESH3D-M3

Mounting Pad Layout

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



0.126 (3.20) MIN.



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